



**RS1A THRU RS1M**  
SURFACE MOUNT FAST  
SWITCHING RECTIFIER

TECHNICAL  
SPECIFICATION

**VOLTAGE: 50 TO 1000V CURRENT: 1.0A**

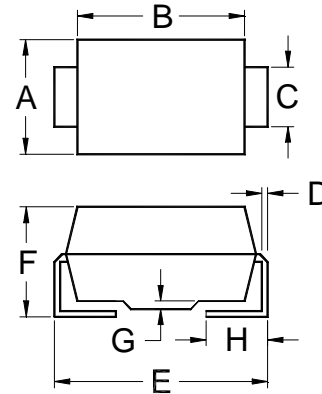
**FEATURES**

- Ideal for surface mount pick and place application
- Low profile package
- Built-in strain relief
- High surge capability
- Glass passivated chip
- Fast recovery for high efficiency
- High temperature soldering guaranteed: 260°C/10sec/at terminal

**MECHANICAL DATA**

- Terminal: Plated leads solderable per MIL-STD 202E, method 208C
- Case: Molded with UL-94 Class V-O recognized flame retardant epoxy
- Polarity: Color band denotes cathode

**SMA/DO-214AC**



	A	B	C	D
MAX.	.110(2.79)	.177(4.50)	.058(1.47)	.012(0.305)
MIN.	.100(2.54)	.157(3.99)	.052(1.32)	.006(0.152)
	E	F	G	H
MAX.	.208(5.28)	.090(2.29)	.008(0.203)	.060(1.52)
MIN.	.194(4.93)	.078(1.98)	.004(0.102)	.030(0.76)

Dimensions in inches and (millimeters)

**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

RATINGS	SYMBOL	RS 1A	RS 1B	RS 1D	RS 1G	RS 1J	RS 1K	RS 1M	UNITS
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current ( $T_L=110^\circ\text{C}$ )	$I_{F(AV)}$	1.0							A
Peak Forward Surge Current (8.3ms single half sine-wave superimposed on rated load)	$I_{FSM}$	30							A
Maximum Instantaneous Forward Voltage (at rated forward current)	$V_F$	1.3							V
Maximum DC Reverse Current ( $T_a=25^\circ\text{C}$ )	$I_R$	5.0							$\mu\text{A}$
(at rated DC blocking voltage) ( $T_a=125^\circ\text{C}$ )		200							$\mu\text{A}$
Maximum Reverse Recovery Time (Note 1)	$t_{rr}$	150				250	500		nS
Typical Junction Capacitance (Note 2)	$C_J$	15							pF
Typical Thermal Resistance (Note 3)	$R_{\theta(ja)}$	30							$^\circ\text{C/W}$
Storage and Operation Junction Temperature	$T_{STG}, T_J$	-50 to +150							$^\circ\text{C}$

Note:

- 1.Reverse recovery condition  $I_F=0.5\text{A}$ ,  $I_R=1.0\text{A}$ ,  $I_{rr}=0.25\text{A}$ .
- 2.Measured at 1.0 MHz and applied voltage of 4.0V<sub>dc</sub>
- 3.Thermal resistance from junction to terminal mounted on 5x5mm copper pad area